SLLS810-JULY 2007

FEATURES

- ESD Protection for RS-232 I/O Pins
 ±15-kV Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V V_{CC} Supply
- Four Drivers and Four Receivers
- Operates up to 120 kbit/s
- External Capacitors . . . 4 × 0.1 μF
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

DB, DW, OR NT PACKAGE (TOP VIEW) 24 DOUT3 DOUT2 DOUT1 23 RIN3 RIN2 22 ROUT3 21 DIN4 ROUT2 20 DOUT4 DIN1 6 19 DIN3 ROUT1 RIN1 18∏ DIN2 17∏ ROUT4 GND 8 16 RIN4 9 vcc [15∏ _V_ C1+ [11 14 C2-V+ [12 13 C2+

DESCRIPTION/ORDERING INFORMATION

The TRS208 device consists of four line drivers, four line receivers, and a dual charge-pump circuit with ± 15 -kV HBM ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The devices operate at data signaling rates up to 120 kbit/s and a maximum of 30-V/ μ s driver output slew rate.

ORDERING INFORMATION

T _A	PAC	(AGE ⁽¹⁾⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – NT	Tube of 15	TRS208CNT	PREVIEW
	SOIC - DW	Tube of 25	TRS208CDW	- TRS208C
0°C to 70°C	30IC - DW	Reel of 2000	TRS208CDWR	1K3206C
	SSOP – DB	Tube of 60	TRS208CDB	RU08C
	220b – DB	Reel of 2000	TRS208CDBR	RUUSC
	PDIP – NT	Tube of 15	TRS208INT	PREVIEW
	SOIC - DW	Tube of 25	TRS208IDW	TRS208I
–40°C to 85°C	30IC - DW	Reel of 2000	TRS208IDWR	1832001
	SSOP – DB	Tube of 60	TRS208IDB	- RU08I
	330F - DB	Reel of 2000	TRS208IDBR	RUUOI

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

⁽²⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION





FUNCTION TABLES

Each Driver(1)

INPUT DIN	OUTPUT DOUT
L	Н
Н	L

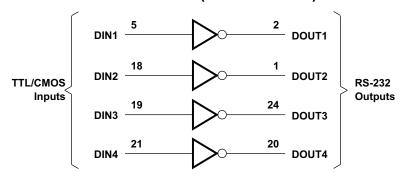
(1) H = high level, L = low level

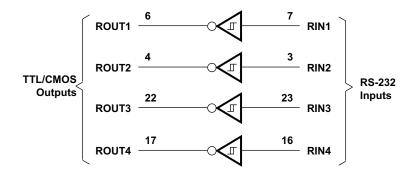
Each Receiver⁽¹⁾

INPUT RIN	OUTPUT ROUT
L	Н
Н	L
Open	Н

(1) H = high level, L = low level,Open = input disconnected or connected driver off

LOGIC DIAGRAM (POSITIVE LOGIC)





TRS208 5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ± 15 -kV ESD PROTECTION

SLLS810-JULY 2007

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive charge pump voltage range (2)		V _{CC} - 0.3	14	V
V-	Negative charge pump voltage range ⁽²⁾		-14	0.3	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
M	land to alternative	Drivers	-0.3	V+ + 0.3	V
V _I	Input voltage range	Receivers		±30	V
M	Output valtage reage	Drivers	V0.3	V+ + 0.3	V
Vo	Output voltage range	Receivers	-0.3	V _{CC} + 0.3	V
	Short-circuit duration	DOUT		Continuous	
		DB package (3)(4)		63	
θ_{JA}	Package thermal impedance	DW package ⁽³⁾⁽⁴⁾		46	°C/W
		NT package (3) (5)		67	
T _J	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network GND.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

See Figure 4

			MIN	NOM	MAX	UNIT
	Supply voltage		4.5	5	5.5	V
V_{IH}	Driver high-level input voltage	DIN	2			V
V_{IL}	Driver low-level input voltage	DIN			0.8	V
V	Driver input voltage	DIN	0		5.5	V
VI	Receiver input voltage		-30		30	V
т	Operating free air temperature	TRS208C	0		70	°C
I A	Operating free-air temperature TRS208I				85	

⁽¹⁾ Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V \pm 0.5 V.

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
I _{CC}	Supply current	No load,	$V_{CC} = 5 V$,	$T_A = 25^{\circ}C$		11	20	mA

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

⁽³⁾ Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

⁽⁵⁾ The package thermal impedance is calculated in accordance with JESD 51-3.

TRS208

5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

SLLS810-JULY 2007



DRIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDIT	IONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	9		V
V _{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = V _{CC}	- 5	-9		V
I _{IH}	High-level input current	$V_I = V_{CC}$			15	200	μΑ
$I_{\rm IL}$	Low-level input current	V _I at 0 V			-15	-200	μΑ
I _{OS} (3)	Short-circuit output current	V _{CC} = 5.5 V,	V _O = 0 V		±10	±60	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V	300			Ω

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CO	TEST CONDITIONS			MAX	UNIT
	Maximum data rate	$C_L = 50 \text{ pF to } 1000 \text{ pF},$ One DOUT switching,	R_L = 3 kΩ to 7 kΩ, See Figure 1	120			kbit/s
t _{PLH(D)}	Propagation delay time, low- to high-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 \text{ k}\Omega$, See Figure 1		2		μs
t _{PHL(D)}	Propagation delay time, high- to low-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 \text{ k}\Omega,$ See Figure 1		2		μs
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 150 pF to 2500 pF, See Figure 2	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$		300		ns
SR(tr)	Slew rate, transition region (see Figure 1)	$C_L = 50 \text{ pF to } 1000 \text{ pF},$ $V_{CC} = 5 \text{ V}$	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	3	6	30	V/µs

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 5 V, and T_A = 25°C.

ESD Protection

PIN	TEST CONDITIONS	TYP	UNIT
DOUT, RIN	Human-Body Model (HBM)	±15	kV

 ⁽²⁾ All typical values are at V_{CC} = 5 V, and T_A = 25°C
 (3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

⁽³⁾ Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.

TRS208 5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

SLLS810-JULY 2007

RECEIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDITIONS	MIN	I TYP	MAX	UNIT
V_{OH}	High-level output voltage	I _{OH} = -1 mA	3.5	;		V
V_{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
$V_{\text{IT+}}$	Positive-going input threshold voltage	$V_{CC} = 5 \text{ V}, \qquad T_A = 25^{\circ}\text{C}$		1.7	2.4	V
$V_{\text{IT-}}$	Negative-going input threshold voltage	$V_{CC} = 5 \text{ V}, \qquad T_A = 25^{\circ}\text{C}$	0.0	1.2		V
V_{hys}	Input hysteresis (V _{IT+} – V _{IT-})	V _{CC} = 5 V	0.2	2 0.5	1	V
r _i	Input resistance	$V_1 = \pm 3 \text{ V to } \pm 25 \text{ V}, V_{CC} = 5 \text{ V}, \qquad T_A = 2$	5°C 3	5	7	kΩ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

Switching Characteristics⁽¹⁾

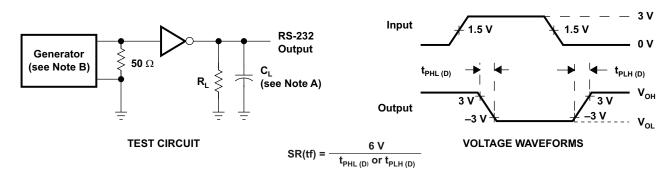
over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 3)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
t _{PLH(R)}	Propagation delay time, low- to high-level output	$C_{L} = 150 \text{ pF}$		0.5	10	μs
t _{PHL(R)}	Propagation delay time, high- to low-level output	$C_{L} = 150 \text{ pF}$		0.5	10	μs
t _{sk(p)}	Pulse skew ⁽³⁾			300		ns

 ⁽¹⁾ Test conditions are C1–C4 = 0.1 µF at V_{CC} = 5 V ± 0.5 V.
 (2) All typical values are at V_{CC} = 5 V, and T_A = 25°C.
 (3) Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.



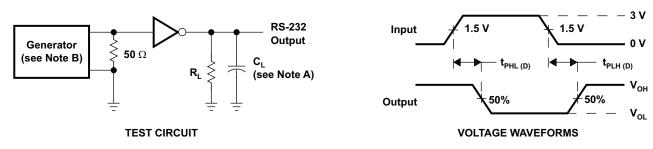
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, Z_0 = 50 Ω , 50% duty cycle, $t_r \le$ 10 ns, $t_f \le$ 10 ns.

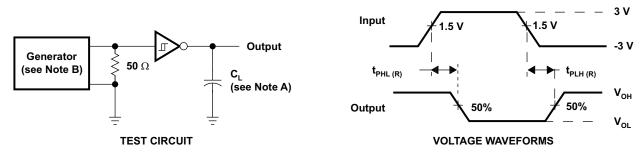
Figure 1. Driver Slew Rate



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns.

Figure 2. Driver Pulse Skew



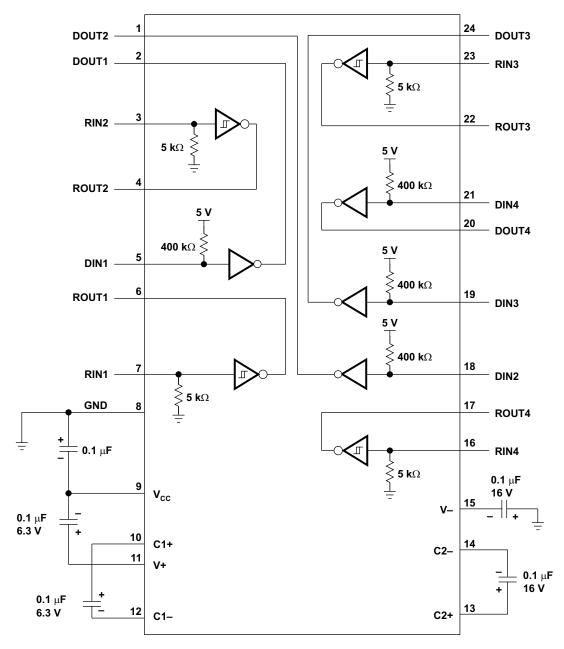
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times



APPLICATION INFORMATION



NOTES: A. Resistor values shown are nominal.

B. Non-polarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 4. Typical Operating Circuit and Capacitor Values

SLLS810-JULY 2007



APPLICATION INFORMATION (continued)

Capacitor Selection

The capacitor type used for C1–C4 is not critical for proper operation. The TRS208 requires $0.1-\mu F$ capacitors, although capacitors up to $10~\mu F$ can be used without harm. Ceramic dielectrics are suggested for the $0.1-\mu F$ capacitors. When using the minimum recommended capacitor values, ensure that the capacitance value does not degrade excessively as the operating temperature varies. If in doubt, use capacitors with a larger (e.g., $2\times$) nominal value. The capacitors' effective series resistance (ESR), which usually rises at low temperatures, influences the amount of ripple on V+ and V-.

Use larger capacitors (up to 10 µF) to reduce the output impedance at V+ and V-.

Bypass V_{CC} to ground with at least 0.1 μ F. In applications sensitive to power-supply noise generated by the charge pumps, decouple V_{CC} to ground with a capacitor the same size as (or larger than) the charge-pump capacitors (C1–C4).

Electrostatic Discharge (ESD) Protection

TI TRS208 devices have standard ESD protection structures incorporated on the pins to protect against electrostatic discharges encountered during assembly and handling. In addition, the RS-232 bus pins (driver outputs and receiver inputs) of these devices have an extra level of ESD protection. Advanced ESD structures were designed to successfully protect these bus pins against ESD discharge of ± 15 kV when powered down.

ESD Test Conditions

ESD testing is stringently performed by TI, based on various conditions and procedures. Please contact TI for a reliability report that documents test setup, methodology, and results.

Human-Body Model (HBM)

The HBM of ESD testing is shown in Figure 5, while Figure 6 shows the current waveform that is generated during a discharge into a low impedance. The model consists of a 100-pF capacitor, charged to the ESD voltage of concern and subsequently discharged into the DUT through a 1.5-k Ω resistor.

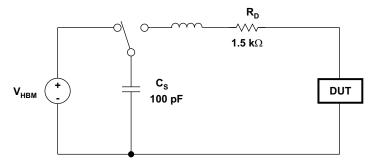


Figure 5. HBM ESD Test Circuit

www.ti.com

SLLS810-JULY 2007

APPLICATION INFORMATION (continued)

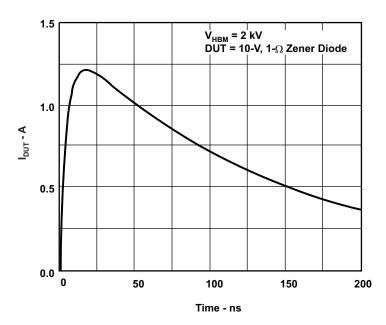


Figure 6. Typical HBM Current Waveform

Machine Model (MM)

The MM ESD test applies to all pins using a 200-pF capacitor with no discharge resistance. The purpose of the MM test is to simulate possible ESD conditions that can occur during the handling and assembly processes of manufacturing. In this case, ESD protection is required for all pins, not just RS-232 pins. However, after PC board assembly, the MM test no longer is as pertinent to the RS-232 pins.



24-Jul-2010

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TRS208CDB	ACTIVE	SSOP	DB	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TRS208CDBG4	ACTIVE	SSOP	DB	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TRS208CDBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRS208CDBRG4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRS208CDW	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	Purchase Samples
TRS208CDWG4	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	Purchase Samples
TRS208CDWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRS208CDWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRS208IDB	ACTIVE	SSOP	DB	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TRS208IDBG4	ACTIVE	SSOP	DB	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TRS208IDBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Sample
TRS208IDBRG4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Sample
TRS208IDW	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	Purchase Samples
TRS208IDWG4	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	Purchase Samples
TRS208IDWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Sample
TRS208IDWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Sample

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.



PACKAGE OPTION ADDENDUM

24-Jul-2010

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

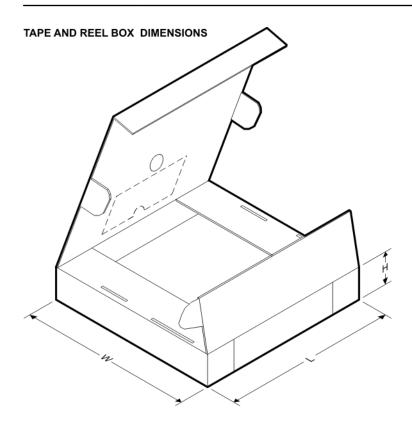
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS208CDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
TRS208CDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
TRS208IDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
TRS208IDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS208CDBR	SSOP	DB	24	2000	346.0	346.0	33.0
TRS208CDWR	SOIC	DW	24	2000	346.0	346.0	41.0
TRS208IDBR	SSOP	DB	24	2000	346.0	346.0	33.0
TRS208IDWR	SOIC	DW	24	2000	346.0	346.0	41.0

DW (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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